



# Proof of Concept of the Quantum Capacitance Detector

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## **Single Cooper-Pair Box**



Electrostatic gate charge 
$$n_G = \frac{C_G V_G}{2e}$$

Charging energy

$$E_C = \frac{e^2}{2C_{\Sigma}}$$

Josephson coupling 
$$E_J = E_J$$

$$E_J = E_J^{\max} \left| \cos \left( \frac{\pi \Phi}{\Phi_o} \right) \right|$$

$$H = 4E_C \sum_n (n - n_G)^2 |n\rangle \langle n| - \frac{E_J}{2} \sum_n (|n + 1\rangle \langle n| + |n\rangle \langle n + 1|)$$





## Energy levels, Coulomb Staircase and Quantum Capacitance

• In the absence of Josephson coupling, Energy is given by parabolas centered at integer values of Cooper Pair Charge

$$E = (Q - 2ne)^2 = (C_g V_g - 2ne)^2$$

• As the gate voltage is increased, Cooper Pairs tunnel to minimize the energy and the charge on the island changes in a stepwise fashion  $d\langle n \rangle$ 

• The capacitance of the island  $C_Q = 2e \frac{d\langle n \rangle}{dV_g}$  spikes up at the

degeneracy points where the charge in the island is changing fast

- The Josephson Coupling introduces splittings in the energy levels
- Eigenvectors are symmetrical and anti-symmetrical combinations of the charge states
- The larger Ej, the "rounder" the charge staircase and the smaller the capacitance peaks
- In the absence of tunneling, only one parabola would exist (n=0) and the capacitance would be constant as a function of the gate voltage
- The variable capacitance is due to the quantum nature of the system and is called the quantum capacitance







### **Quasiparticle Poisoning**



• If there are quasiparticles present in the leads, they could tunnel in and out of the island

• When they tunnel, they shift the effective gate voltage by e/Cg (or ng=0.5)

• Coulomb staircase and quantum capacitance curve shifts by ng=0.5 each time a quasiparticle tunnels in or out.







## **Measurement Technique**



- Change in capacitance pulls the frequency of the oscillator
- Resonant frequency (~600 MHz) is far below qubit level spacing (~5 GHz)
- Noise and RF probe isolated from qubit
- Overall circuit capacitance is determined by qubit state
- Enables elegant multiplexing of many qubits
- Phase shift is measured with quadrature mixer





## **Measurement Technique**



- In actual detectors we will use  $\lambda/2$  resonator capacitively coupled to a feedline
- SCB si the variable capacitor at the end of resonator





## **Experimental Setup**





• Two SCBs with multiplexed quantum capacitance readout





## **Experimental measurements**







## **Tunnel Rate Measurements**



- Phase measured at degeneracy point in real time
- One quasiparticle tunnel event shifts phase by ~140 degrees
- Can study statistics and compare with existing theory





## **Dependence on Quasiparticle Density**

$$\Gamma_{in} \approx K n_{qp}$$
  $\Gamma_{out}$  independent of  $n_{qp}$ 

$$K = \frac{G_N}{e^2} \frac{e^{\Delta_L/kT}}{N_L} \int_{\max(\Delta_I - \delta E, \Delta_L)}^{\infty} dE \frac{E(E + \delta E) - \Delta_L \Delta_I}{\sqrt{((E + \delta E)^2 - \Delta_I^2)(E^2 - \Delta_L^2)}} e^{-E/kT}$$

• Approximations valid at low temperature

• Simple relationship between rates and QP density is ideal for detector

$$P_{odd} = \frac{\Gamma_{in}}{\Gamma_{in} + \Gamma_{out}}$$





#### **The Quantum Capacitance Detector**



• Radiation coupled by an antenna breaks Cooper pairs in the reservoir (absorber)

• Quasiparticles tunnel onto the island with a rate  $\Gamma_{\text{in}}$  proportional to the quasiparticle density in the reservoir

• Quasiparticles tunnel out of the island with a rate  $\Gamma_{out}$  independent of the number of quasiparticles in the reservoir

• At steady state the probability of a quasiparticle being present in the island is given by *Po(Nqp)=Γin/(Γin+Γout,)* 

• The resulting change in the average capacitance will be  $C_Q = (4E_C/E_J)(C_g^2/C_\Sigma)Po(Nqp)$ 

• This change in capacitance will produce a phase shift  $\delta \Phi \sim 2C_Q / (\omega_o Z_o C_C^2)$ 

• With the existing tank circuit parameters, phase shift per quasiparticle should be 138 degrees, in very good agreement with experiments





#### Noise Sources and NEP

10-18

• Phase noise - from phase measurement histogram the rms phase noise is  $\sim 33$ degrees or 1.8x10<sup>-3</sup> radian/Hz<sup>1/2</sup> over the 100kHz bandwidth

 Telegraph noise: the tunneling on and off the island is approximated as a Poisson process with rates Feo and Foe. At low frequencies the spectral density of noise associated with the process is

•Fano noise: the number of quasiparticles generated by an incoming photon has an uncertainty given by (FNqp)1/2 where F~0.2 is the Fano factor for this system. The associated NEP is

 Generation-recombination noise: quasiparticles can be thermally excited over the superconducting gap and recombine into Cooper pairs, introducing a fluctuation in the number of quasiparticles in the reservoir The associated NEP is

 The noise equivalent power at low frequencies will be given by

$$S_{\Phi}^{Tele} = \frac{\delta \Phi^2}{\pi} \frac{\Gamma_{eo} \Gamma_{oe}}{\left(\Gamma_{eo} + \Gamma_{oe}\right)^2}$$

 $NEP_{GR} = 2\Delta_L \sqrt{\frac{N_{eq}}{\tau_R}}$ 

N<sub>eq</sub> is the number of equilibrium quasiparticles.

$$N_{eq} = \Omega_L D(E_F) \sqrt{\frac{\pi k_B T \Delta_L}{2}} \exp(-\frac{\Delta}{k_B T})$$

$$NEP = \sqrt{\left(\frac{dP_s}{dN_{qp}}\right)^2 \left(\frac{d\Phi}{dN_{qp}}\right)^{-2} \left(S_{\Phi}^{Phase} + S_{\Phi}^{Tele}\right) + NEP_{GR}^2 + NEP_{FANO}^2}$$





#### **Theoretical Sensitivity**



Left: NEPs from various noise sources calculated for devices optimized for  $\lambda = 100 \mu m$ , optical loading 10<sup>-19</sup> W and R=1000 as a function of temperature. Right: NEPs of various noise sources as a function of wavelength as compared to the requirements for a spectrometer with R=1000 and the expected optical loading at L2 for a cold (4.2K) telecope. The operating temperature was chosen to be 0.1K at which the GR noise contribution is negligible.





## **Theoretical Sensitivity vs. Signal Power**



• Detector is background limited over a wide range of operation





## **Theoretical Sensitivity vs. Absorber Volume**



- Absorber volume is a key parameter
- Can be used to trade sensitivity for saturation power





## **Single Photon Detection**







## **Experimental Confirmation Quasiparticle Injection with SIS junctions**







## Experimental demonstration Response versus signal





- Ran a current through SIS junction to inject quasiparticles on reservoir
- AC component of current simulates signal and DC optical loading
- +  $\tau_{\rm D}$  is the time for quasiparticles to diffuse through constriction
- Graph shows lock-in response as a function of number of quasiparticles present in the reservoir.
- The measured noise in number of quasiparticles in the reservoir was  $\delta Npq~11$  qp/Hz^{1/2}, which would yield an NEP~ 3x10^{-18}W/Hz

$$NEP = \eta \frac{\Delta}{\tau_R} \delta Nqp$$

 $N_{qp} = \frac{I}{e} \left( \frac{1}{\tau_{R}} + \frac{1}{\tau_{D}} \right)^{-1} \sim \frac{I}{e} \tau_{D}$ 





## Experimental demonstration Response x loading







## **Multiplexing scheme**



• Gates are swept with a low frequency *f* signal of amplitude e/Cg

• A mixer demodulates the reflected RF signal to the modulation frequency *f* and a down converter translates the results to DC

• In the multi-pixel readout, A low frequency comb function (0-200MHz) containing several frequency components is produced digitally using a D/A converter and then block up-converted, resulting in a comb of RF carrier frequencies with each frequency corresponding to a particular detector.

• All of the SCB gates are tied together through a common bias line and modulated at the same frequency.

• The reflected RF comb, containing the phase shift information for the entire array, is demodulated at the bias modulation frequency, down-converted to the 0-200MHz band, then digitized and digitally demultiplexed.





## **Applications in FIR-Submillimeter Astronomy**





Cold (4.2K) telescope at L2 with R=1000 spectrometer





## **Detector Advantages**

- SCB has extreme sensitivity to the presence of quasiparticles
- Sensitivity of QCD rivals MKID and TES
- Frequency-domain multiplexing allows scaling to large arrays
- Applicable to submillimeter wavelengths for far-infrared astrophysics
- Can be easily incorporated with existing technology for MKID arrays
- Detector (SCB) is separate from resonator flexibility of design
- NEP and saturation power easily tailorable